NSN 5962-01-186-1982

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-186-1982

Overall Length:
1.110 inches
Overall Height:
0.360 inches
Body Length:
1.110 inches
Body Width:
Between 0.280 inches and 0.310 inches
Body Height:
0.185 inches
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and bipolar and schottky and positive outputs
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Current Rating Per Characteristic:
185.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
5.00 input picofarads and 12.00 output picofarads
Time Rating Per Chacteristic:
65.00 nanoseconds delay
Memory Device Type:
Prom
Memory Capacity:
Unknown
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a

NSN 5962-01-186-1982

Memory Microcircuit - Page 2 of 2



Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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